

Effects of colored disorder on the heat conductivity of SiGe alloys from first principles

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Introduction

Lattice thermal conductivity is critical for the performance of silicon-based thermoelectric (TE) devices.

► Thermoelectric figure of merit

$$ZT = \frac{\sigma S^2 T}{\kappa}$$

Thermal conductivity $\kappa = \kappa^{el} + \kappa^l$. For TE devices based on doped silicon, $\kappa \approx \kappa^l$.

The lattice thermal conductivity is estimated through the **Quasi-Harmonic Green-Kubo** formula:

$$\kappa^l = \frac{1}{3V} \sum_{\mu\mu'} C_{\mu\mu'} |v_{\mu\mu'}|^2 \frac{\gamma_\mu + \gamma_{\mu'}}{(\omega_\mu - \omega_{\mu'})^2 + (\gamma_\mu + \gamma_{\mu'})^2}$$

where γ_μ is the normal mode linewidth, $\langle \hat{a}_\mu^\dagger(t) \hat{a}_\mu \rangle \approx (n_\mu + 1) e^{i\omega_\mu t - \gamma_\mu |t|}$

Alloying with germanium **enhances** thermoelectric performance by **reducing** lattice thermal conductivity. The introduction of spatially correlated (colored) disorder [2] can further improve this effect.

Hydrodynamic extrapolation

QHGK is computationally expensive for disordered systems $\sim O(N^3)$.

$$\kappa_{\text{hydro}} = \kappa_P + \kappa_D$$

$$\kappa_P = \frac{1}{3V} \sum_{\mathbf{qb}} C_{\mathbf{qb}} |v_{\mathbf{qb}}|^2 \frac{1}{2\Gamma_{\mathbf{qb}}} \Theta(\omega_P - \omega_{\mathbf{qb}})$$

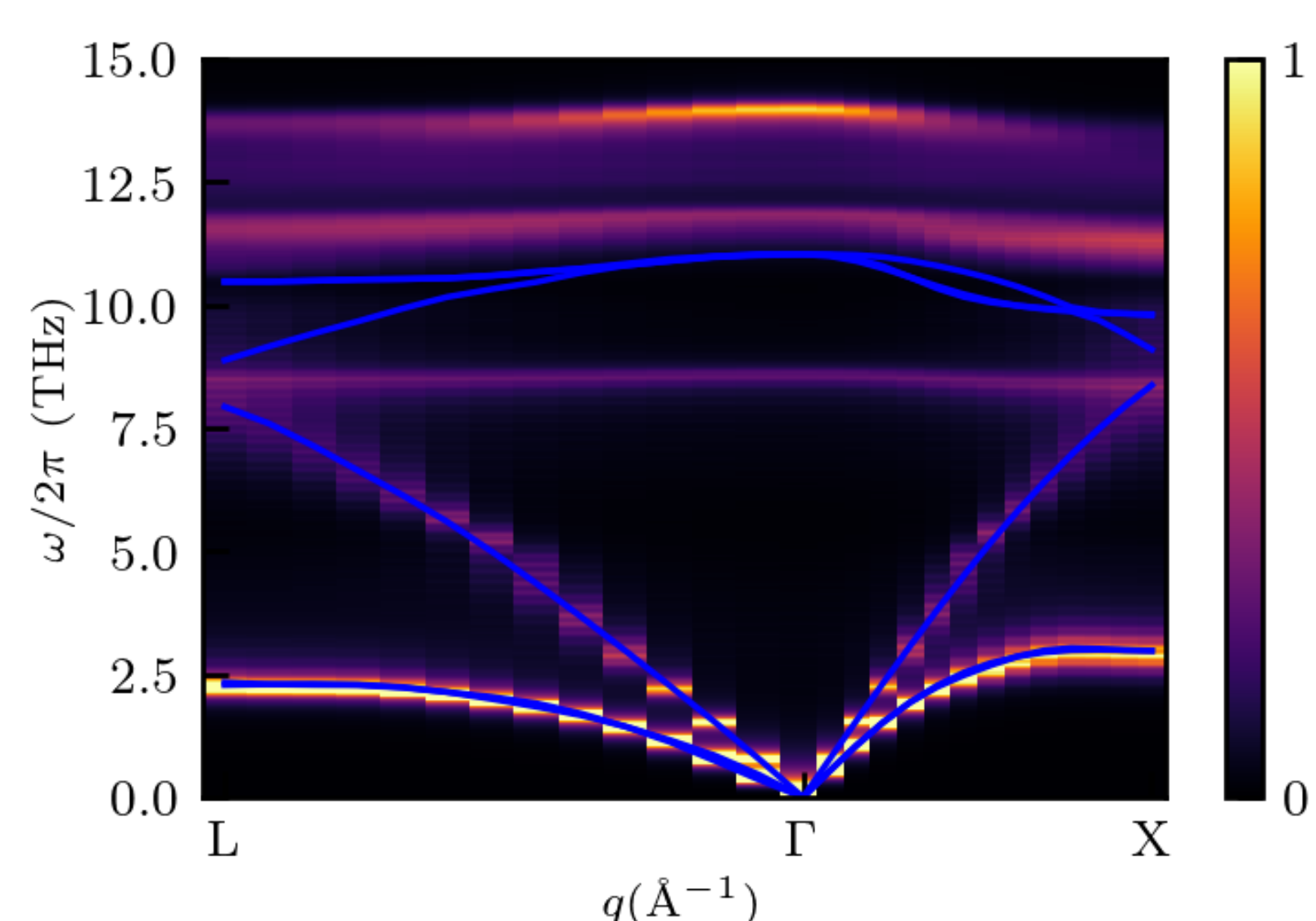
$$\kappa_D = \sum_{\mu\mu'} \frac{C_{\mu\mu'}}{3V} |v_{\mu\mu'}|^2 \tau_{\mu\mu'} \Theta(\omega_\mu - \omega_P) \Theta(\omega_{\mu'} - \omega_P)$$

κ_D is computed on small samples, $N \lesssim 10^4$.

κ_P is modeled effectively using the Vibrational Dynamical Structure Factor [3,4].

$$S_{\mathbf{qb}}(\omega) = \sum_{\mu} \frac{1}{\pi \gamma_\mu^2 + (\omega - \omega_\mu)^2} |\langle \mu | \mathbf{qb} \rangle|^2$$

$$\approx \frac{A_{\mathbf{qb}}}{\pi} \frac{\Gamma_{\mathbf{qb}}}{(\omega - \omega_{\mathbf{qb}})^2 + \Gamma_{\mathbf{qb}}^2},$$



Computationally inexpensive $\sim O(N)$.
Affordable size $N > 10^5$.

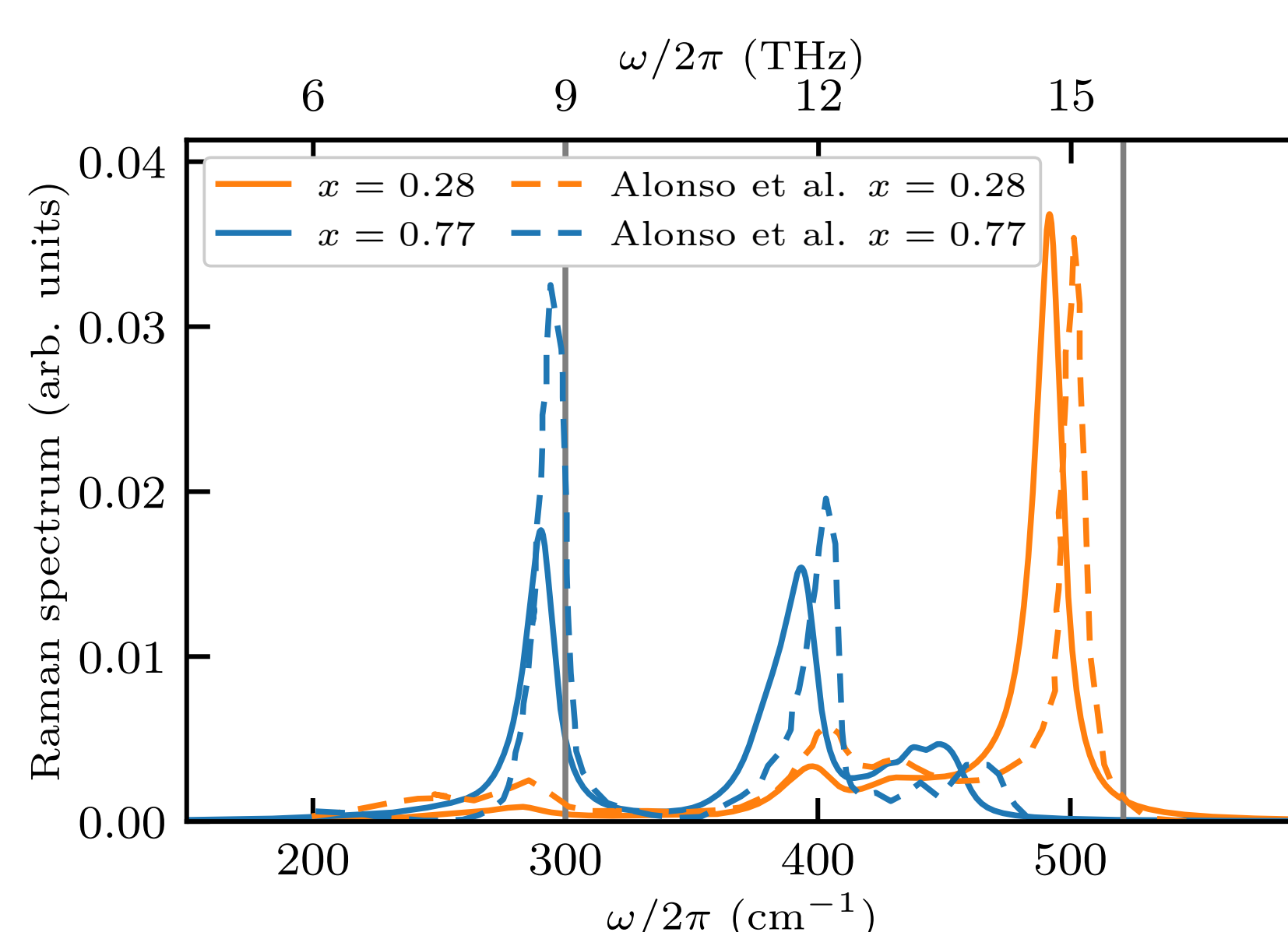
First-principles interatomic force constants

Density Functional Theory electronic virtual crystal approximation

$$\bar{D}_{IJ}^e(x) = \frac{1}{\sqrt{M_I M_J}} \frac{\partial^2 U_x}{\partial R_I \partial R_J}$$

$$U_x = (1-x)U_{\text{Si}} + xU_{\text{Ge}}$$

Material characterization with Raman spectroscopy



Spatially correlated alloy

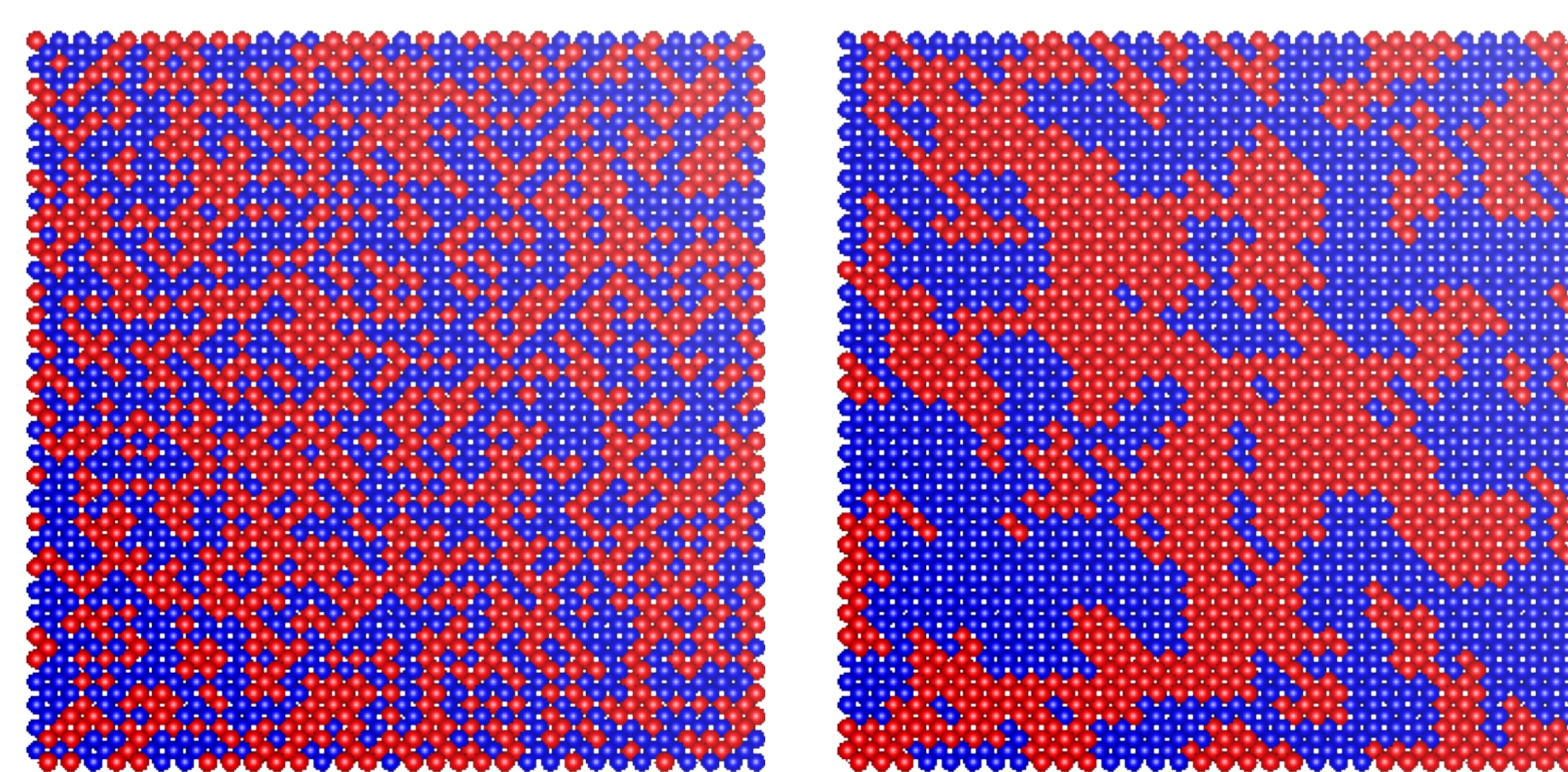
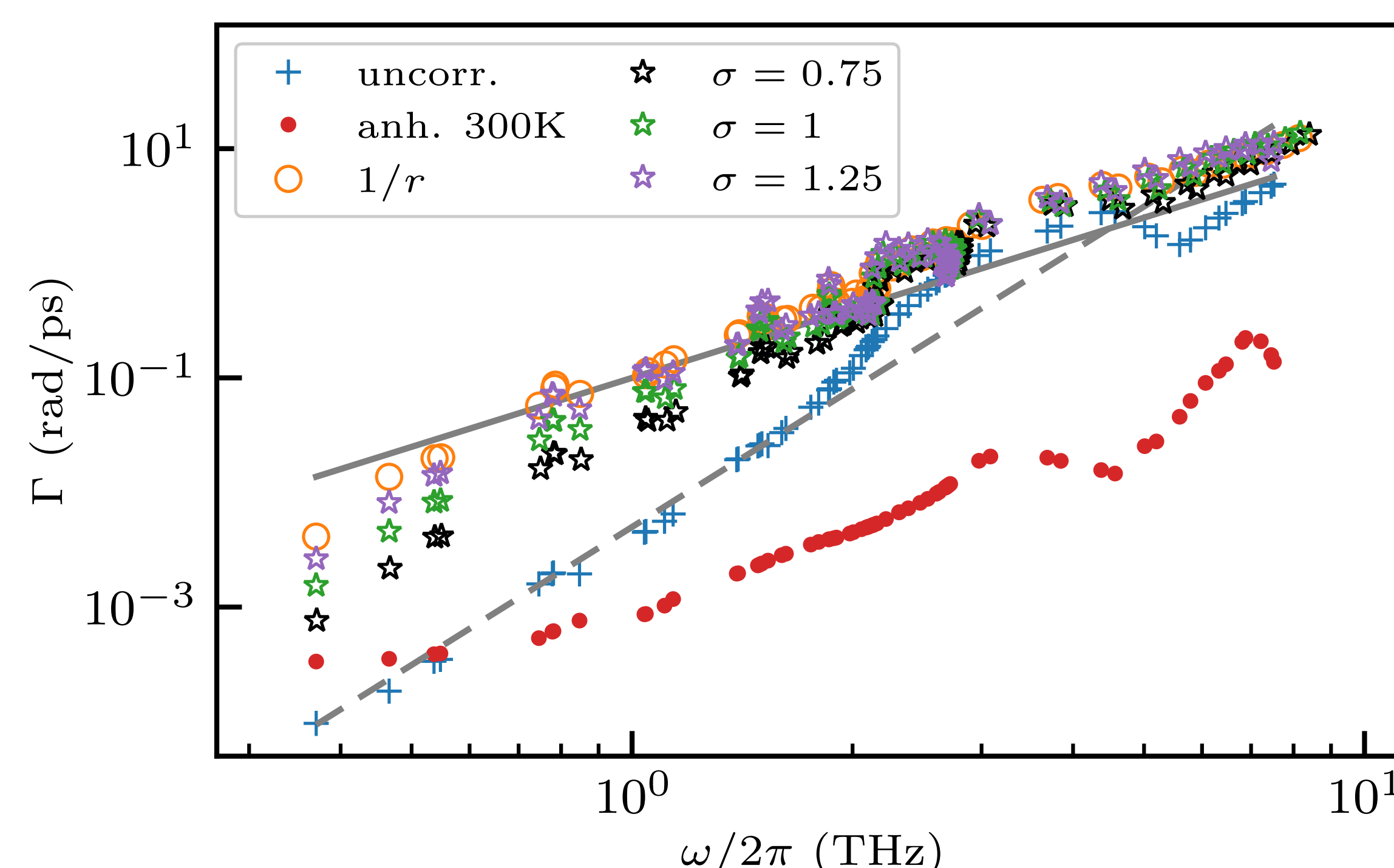


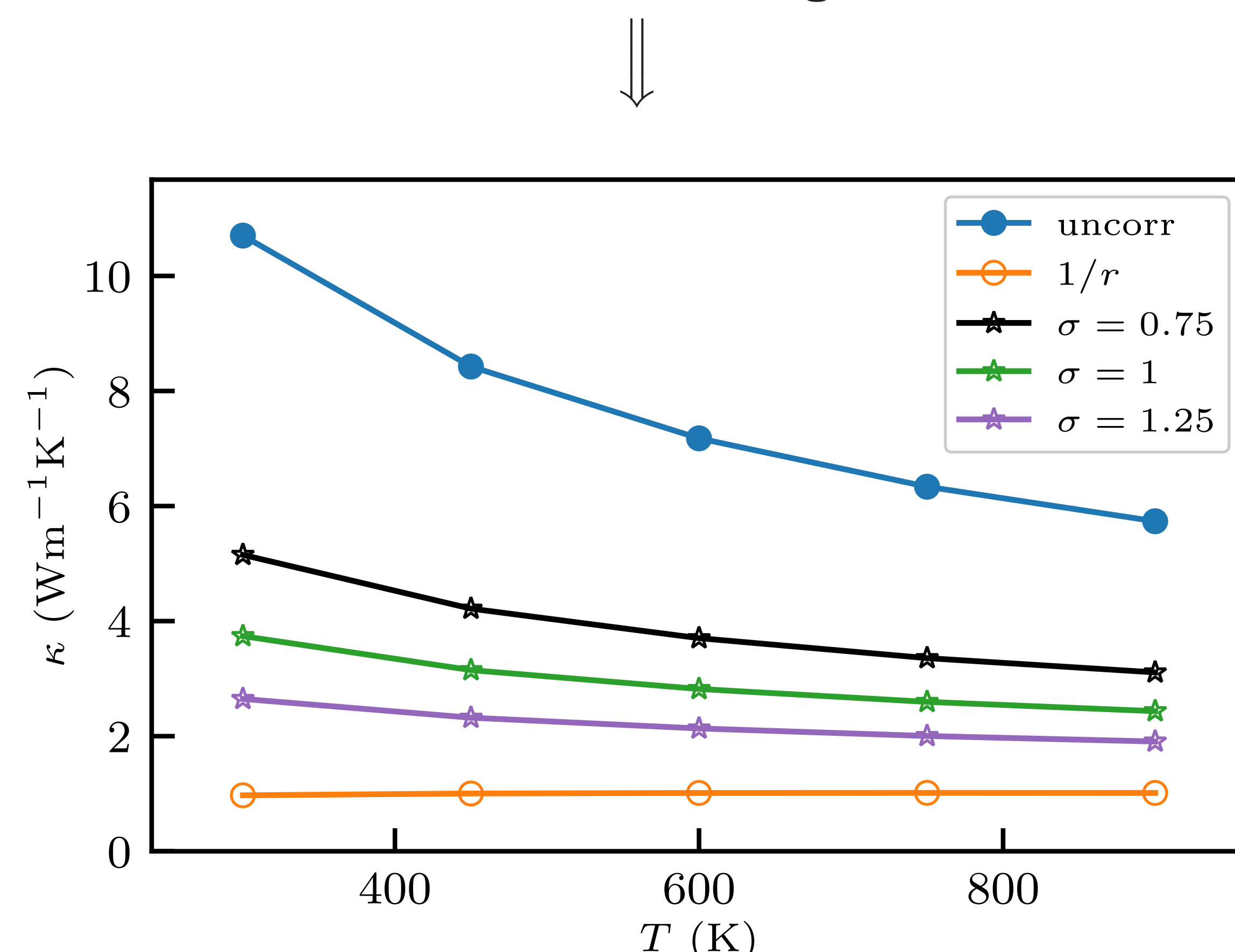
Figure: Left panel: uncorrelated. Right panel: spatially correlated (Gaussian).

$$C(\mathbf{r}) \propto \frac{1}{N} \sum_{I,J=1}^N \delta M(\mathbf{R}_J) \delta M(\mathbf{R}_I) \delta(\mathbf{r} - \mathbf{R}_{IJ})$$

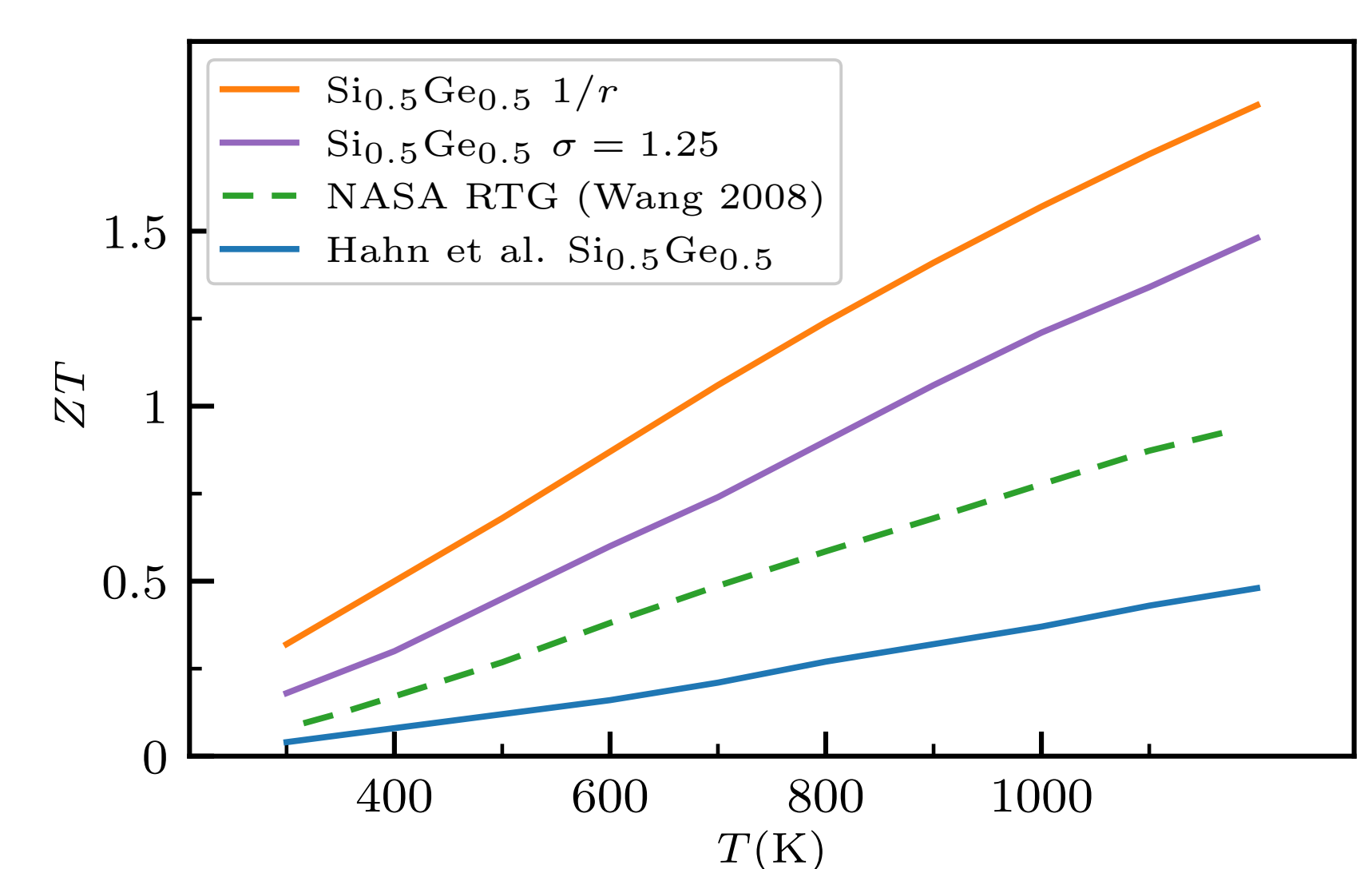
Enhanced sound attenuation and thermal conductivity reduction



Frequency shift of the $\omega^4 \rightarrow \omega^2$ crossover. Overall, the sound attenuation due to colored disorder is **larger**.



Thermoelectric figure of merit



ZT enhancement

- ≈ 4 -fold with respect to white disorder
- ≈ 1.5 with respect to NASA RTG.

Conclusions

- Combining the QHGK formula with hydrodynamic extrapolation offers a robust workflow for calculating the thermal conductivity of disordered systems and nanostructures.
- Spatially correlated disorder induces a crossover in sound attenuation, validating predictions for glasses and deepening insights into vibrational dynamics.
- Spatially correlated SiGe alloys could surpass state-of-the-art thermoelectric devices, advancing TE applications.

References

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- [2] S. Thebaud, L. Lindsay, and T. Berlijn, Phys. Rev. Lett. 131, 026301 (2023).
- [3] [A. F.](#), P. Pegolo and S. Baroni, Npj Comput. Mater. 9, 157 (2023).
- [4] [A. F.](#), E. Drigo, S. Baroni and P. Pegolo, Phys. Rev. B 109, 224202 (2024).

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